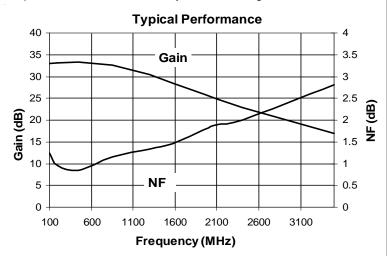


### **Product Description**

The SGL-0622 is a low power, high gain, fully matched LNA designed for 0.1 - 4GHz operation. This LNA is designed for low power, 2.7 to 3.6V battery operation. This amplifer is fully matched and requires only 4-5 external components to achieve 28.5 dB gain at 1.575 GHz and a noise figure of 1.5dB. This RFIC is fabricated using Silicon Germanium technology.

The matte tin finish on Sirenza's lead-free "Z" package is applied using a post annealing process to mitigate tin whisker formation and is RoHS compliant per EU Directive 2002/95. The package body is manufactured with green molding compounds that contain no antimony trioxide or halogenated fire retardants.

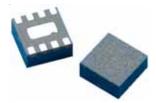


#### Preliminary

**SGL-0622Z** 



# 100 - 4000 MHz Low Noise Amplifier Silicon Germanium



#### **Product Features**

- Lead Free, RoHS Compliant & Green Package
- High Gain and Low Noise,
   28.5dB and 1.5dB respectively @ 1575MHz
- Low Power Consumption, 9mA @ 3.3V
- Fully Matched LNA, only 4-5 external components
- Operates from 2.7 to 3.6V
- Small Package: 2x2 QFN
- High input overdrive capability, +18dBm

#### **Applications**

- High Gain GPS Receivers
- ISM & WIMAX LNAs

Symbol	Parameters	Units	Frequency	Min.	Тур.	Max.
S <sub>21</sub>	Small Signal Gain	dB	1.575 GHz 2.44 GHz 3.5 GHz		28.5 23 17	
NF	Noise Figure	dB	1.575 GHz 2.44 GHz 3.5 GHz		1.50 2 2.8	
P <sub>1dB</sub>	Output Power at 1dB Compression	dBm	1.575 GHz 2.44 GHz 3.5 GHz		5.3 1.5 -1.4	
IIP <sub>3</sub>	Input Third Order Intercept Point	dBm	1.575 GHz 2.44 GHz 3.5 GHz		-13 -12 -8.5	
IRL	Input Return Loss	dB	1.575 GHz 2.44 GHz 3.5 GHz		14.3 12.0 10.0	
ORL	Output Return Loss	dB	1.575 GHz 2.44 GHz 3.5 GHz		9.5 14.0 22.0	
S12	Reverse Isolation	dB	0.05 - 4 GHz		-28	
I <sub>D</sub>	Operating Current	mA		7.5	10.5	12.5

**Test Conditions:** 

 $V_{CC} = 3.3V$   $T_L = 25^{\circ}C$ 

 $I_D = 10.5 \text{mA Typ.}$  $Z_S = Z_L = 50 \text{ Ohms.}$  IIP<sub>3</sub> Tone Spacing = 1MHz, Pout per tone = -15 dBm

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Phone: (800) SMI-MMIC



### Typical RF Performance at Key Operating Frequencies (With Application Circuit)

		Frequency (MHz)								
Symbol	Parameter	Unit	100	200	450	850	1575	1950	2440	3500
S <sub>21</sub>	Small Signal Gain	dB	34.6	34.9	34.4	32.8	28.5	26.1	23.0	17.0
IIP <sub>3</sub>	Input Third Order Intercept Point	dBm					-13.0		-12.0	-8.5
P <sub>1dB</sub>	Output at 1dB Compression	dBm					5.3		1.5	-1.4
S <sub>11</sub>	Input Return Loss	dB	15.1	20.0	12.6	16.0	14.3	12.8	12.0	10.0
S <sub>22</sub>	Output Return Loss	dB	9.2	12.2	11.8	10.4	9.5	12.1	14.0	22.0
S <sub>12</sub>	Reverse Isolation	dB	38.8	39.8	38.7	39.9	35.6	34.8	32.0	29.0
NF	Noise Figure	dB	1.25	0.96	0.84	1.16	1.50	1.78	2.01	2.81

**Fest Conditions:**  $V_{CC} = 3.3V$ 

 $T_L = 25^{\circ}C$ 

 $I_D = 10.5 \text{ mA Typ.}$  $Z_S = Z_L = 50 \text{ Ohms}$  IIP<sub>3</sub> Tone Spacing = 1MHz, Pout per tone = -15 dBm

Reliability & Qualification Information				
Parameter	Rating			
ESD Rating - Human Body Model (HBM)	Class 1C			
Moisture Sensitivity Level	MSL 1			

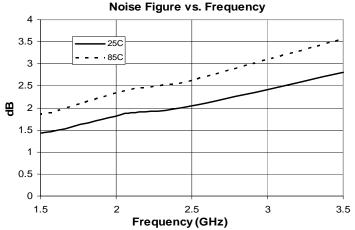
This product qualification report can be downloaded at www.sirenza.com

### **Absolute Maximum Ratings**

**Note:** Load condition 1,  $Z_L = 50$  Ohms Load condition 2, ZL = 10:1 VSWR

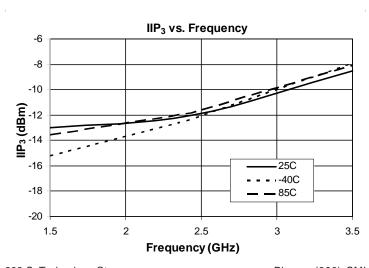
Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one.

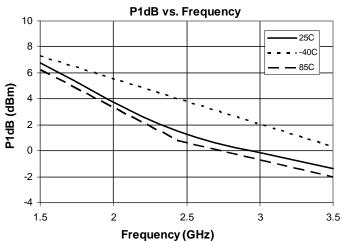
Bias Conditions should also satisfy the following expression:  $I_DV_D < (T_J - T_L) / R_{TH}$ , j-l  $T_L = T_{LEAD}$ 



#### Caution: ESD sensitive

Appropriate precautions in handling, packaging and testing devices must be observed.





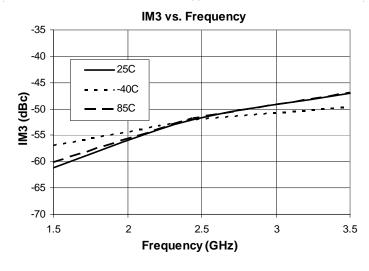
303 S. Technology Ct. Broomfield, CO 80021

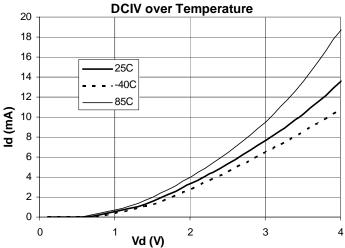
Phone: (800) SMI-MMIC

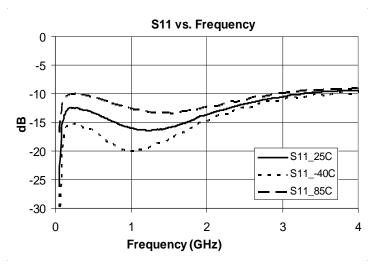
http://www.sirenza.com

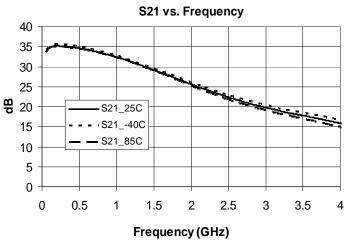


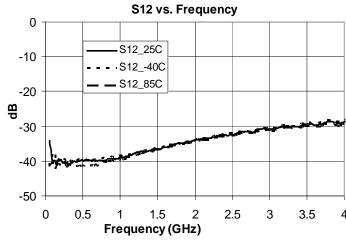
## Application Circuit Data, $V_{CC}$ = 3.3V, $I_{D}$ = 9mA

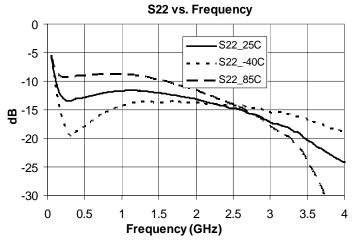








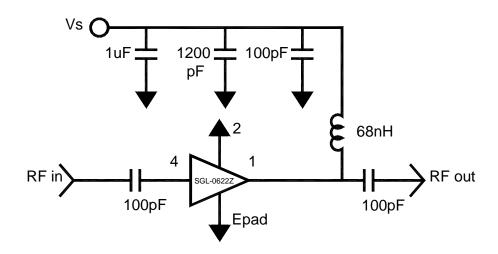




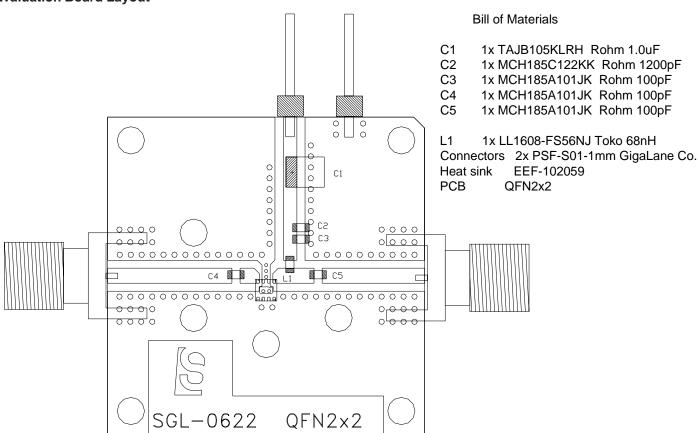
Phone: (800) SMI-MMIC 3



#### **Application Schematic**



#### **Evaluation Board Layout**



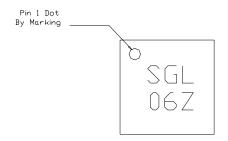


Pin#	Function	Description		
1	RF OUT/V <sub>D</sub>	RF output and bias pin. Bias should be supplied to this pin through an external RF choke. (See application circuit)		
2	GND	Connect to ground per application circuit drawing.		
3,5,6,7,8	N/A	Not Used		
4	RF IN	RF input pin. This pin requires the use of an external DC blocking capacitor as shown in the application schematics.		
EPAD	GND	Exposed area on the bottom side of the package needs to be soldered to the ground plane of the board for thermal and RF performance. Vias should be located under the EPAD as shown in the recommended land pattern.		

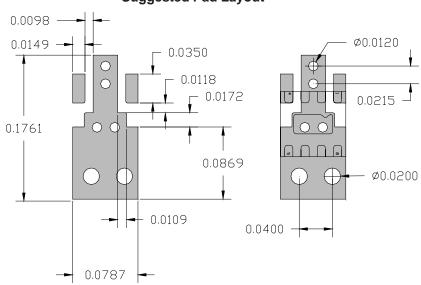
#### **Part Number Ordering Information**

Part Number	Reel Size	Devices / Reel
SGL-0622Z	7"	3000

#### Part Identification

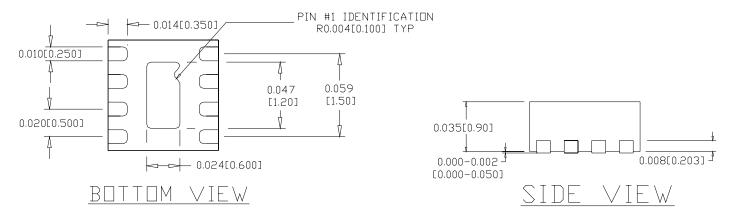


### **Suggested Pad Layout**



#### **Nominal Package Dimensions**

Dimensions in inches [millimeters]
Refer to drawing posted at www.sirenza.com for tolerances.



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